



12/13/01  
1-23-02

PATENT  
Customer No. 22,852  
Attorney Docket No. 04329.2210

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
)  
Katsuhiko HIEDA, et al. ) Group Art Unit: 2811  
)  
Serial No.: 09/469,190 ) Examiner: Hung K. Vu  
)  
Filed: December 21, 1999 )  
)  
For: SEMICONDUCTOR DEVICE AND )  
METHOD FOR )  
MANUFACTURING THE SAME )

Assistant Commissioner for Patents  
Washington, DC 20231

Sir:

AMENDMENT

In reply to the Office Action dated September 13, 2001, the period for response extending through January 14, 2002 (January 13, 2002 being a Sunday) by the attached Petition for Extension of Time of one (1) month and requisite fee payment, please amend the application as follows:

IN THE CLAIMS:

Please amend claims 10 and 19 as follows:

10. (Amended) A semiconductor device comprising:
- a semiconductor substrate;
  - a conductive plug formed on the semiconductor substrate;
  - a lower electrode formed in contact with the conductive plug and constituted by a plurality of crystal grains, the crystal grains containing a metallic element;
  - a capacitor insulating film formed on a side of the capacitor lower electrode; and

LAW OFFICES

FINNEGAN, HENDERSON,  
FARABOW, GARRETT,  
& DUNNER, L.L.P.  
1300 I STREET, N. W.  
WASHINGTON, DC 20005  
202-408-4000